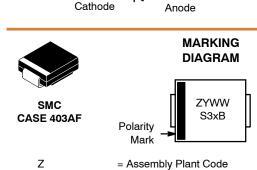


# Rectifiers, Surface Mount, 3 A, 50 V-1000 V

# S3AB-S3MB

#### **Features**

- Glass Passivated Chip Junction
- High Surge Current Capacity
- Low Forward Voltage: 1.15 V Maximum
- UL Flammability 94V-0 Classification
- MSL 1 per J-STD-020
- RoHS Compliant / Green Molding Compound
- NRV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These are Pb-Free and Halide Free Devices



Z Y WW S3xB = Assembly Plant Code= Year

**-0** 2

= Work Week

= Specific Device Code x = A, B, D, G, J, K, M

#### **ORDERING INFORMATION**

See detailed ordering and shipping information on page 3 of this data sheet.

#### **ABSOLUTE MAXIMUM RATINGS** Values are at T<sub>A</sub> = 25°C unless otherwise noted.

		Value							
Symbol	Parameter	S3AB	S3BB	S3DB	S3GB	S3JB	S3KB	S3MB	Unit
$V_{RRM}$	Repetitive Peak Reverse Voltage	50	100	200	400	600	800	1000	V
V <sub>RMS</sub>	RMS Reverse Voltage	35	70	140	280	420	560	700	V
V <sub>R</sub>	DC Blocking Voltage	50	100	200	400	600	800	1000	Α
I <sub>F(AV)</sub>	Average Forward Rectified Current	3				Α			
I <sub>FSM</sub>	Peak Forward Surge Current: 8.3 ms Single Half Sine-Wave Superimposed on Rated Load	80				Α			
$T_J$	Operating Junction Temperature Range	-55 to 150			°C				
T <sub>STG</sub>	Storage Temperature Range	-55 to 150				°C			

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

# **THERMAL CHARACTERISTICS** Values are at $T_A = 25^{\circ}C$ unless otherwise noted. (Note 1)

Symbol	Parameter	Value	Unit
$R_{\theta JA}$	Typical Thermal Resistance, Junction-to-Ambient	148	°C/W
$\Psi_{\sf JL}$	Ψ <sub>JL</sub> Typical Thermal Characteristics, Junction-to-Lead		°C/W

<sup>1.</sup> Device mounted on FR-4 PCB, board size = 76.2 mm x 114.3 mm per JESD51-3.

# **ELECTRICAL CHARACTERISTICS** Values are at T<sub>A</sub> = 25°C unless otherwise noted.

Symbol	Parameter	Test Conditions	Min	Тур	Max	Unit
$V_{F}$	Instantaneous Forward Voltage (Note 2)	I <sub>F</sub> = 3 A	-	_	1.15	V
I <sub>R</sub>	Reverse Current at Rated V <sub>R</sub>	T <sub>J</sub> = 25°C	-	_	10	μΑ
		T <sub>J</sub> = 125°C	-	_	250	
t <sub>rr</sub>	Reverse Recovery Time	I <sub>F</sub> = 0.5 A, I <sub>R</sub> = 1 A, I <sub>rr</sub> = 0.25 A	-	1.5	_	μs
CJ	Junction Capacitance	V <sub>R</sub> = 4 V, f = 1 MHz	-	40	_	pF

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

2. Pulse test with PW = 300 µs, 1% duty cycle.

# TYPICAL PERFORMANCE CHARACTERISTICS

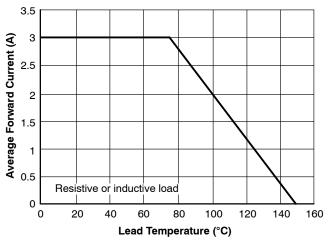


Figure 1. Forward Current Derating Curve

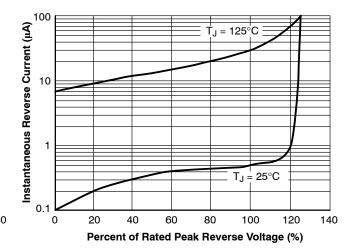


Figure 2. Typical Reverse Characteristics

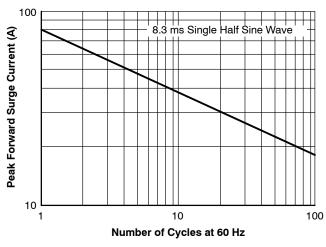


Figure 3. Maximum Non-Repetitive Forward Surge Current

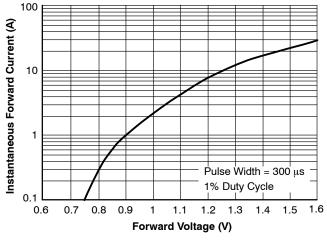


Figure 4. Typical Forward Characteristics

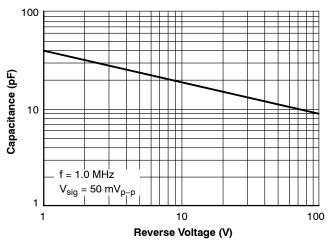


Figure 5. Typical Junction Capacitance

# S3AB-S3MB

# **TEST CIRCUIT DIAGRAM**

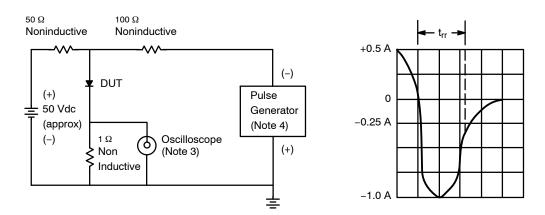


Figure 6. Reverse Recovery Time Characteristic and Test Circuit Diagram

#### NOTES:

- 3. Rise Time = 7 ns max. Input Impedance = 1  $M\Omega$ , 22 pF
- 4. Rise Time = 10 ns max. Source Impedance = 50  $\Omega$ , 22 pF

#### **ORDERING INFORMATION**

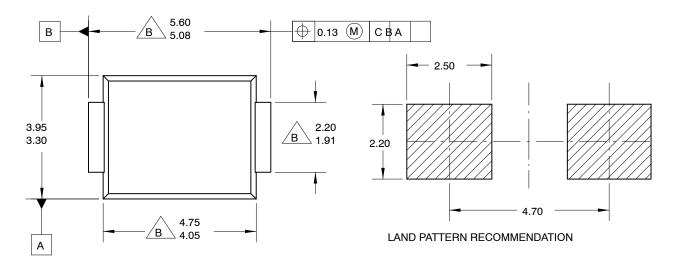
Part Number	Device Code Marking	Package	Shipping <sup>†</sup>		
S3AB, NRVS3AB*	S3AB	SMC 3000 / Tape			
S3BB, NRVS3BB*	S3BB	(Pb-Free, Halide-Free)			
S3DB, NRVS3DB*	S3DB	1			
S3GB, NRVS3GB*	S3GB				
S3JB, NRVS3JB*	S3JB				
S3KB, NRVS3KB*	S3KB	1			
S3MB, NRVS3MB*	S3MB	1			

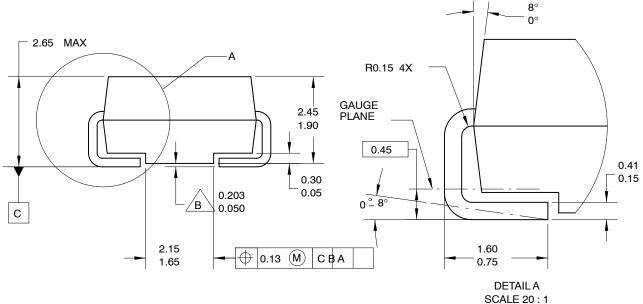
<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, <a href="https://example.com/BRD8011/D">BRD8011/D</a>.

<sup>\*</sup>NRV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable

#### SMB CASE 403AF ISSUE O

**DATE 31 AUG 2016** 





NOTES:

A. EXCEPT WHERE NOTED CONFORMS TO

√ JEDEC DO214 VARIATION AA.

 $/\mathsf{B}\setminus\mathsf{DOES}$  NOT COMPLY JEDEC STD. VALUE.

- C. ALL DIMENSIONS ARE IN MILLIMETERS.
- D. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH AND TIE BAR PROTRUSIONS.
- E. DIMENSION AND TOLERANCE AS PER ASME
- Y14.5-1994.
- F. LAND PATTERN STD. DIOM5336X240M.

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